NSN 5962-01-259-2035

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-259-2035 **Body Length:** 1.400 inches **Body Width:** 0.594 inches **Body Height:** 0.280 inches **Maximum Power Dissipation Rating:** 4.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Low power and hermetically sealed and high speed and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 23 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 120.00 nanoseconds propagation delay time, low to high level output and 120.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig: A458a0

Demilitarization: Yes - demil/mli